



# WILLAS



## PNP Digital Transistor

### DTA123JCA

## Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available
- Built-In Biasing Resistors
- Pb-Free package is available**

RoHS product for packing code suffix "G"

Halogen free product for packing code suffix "H"

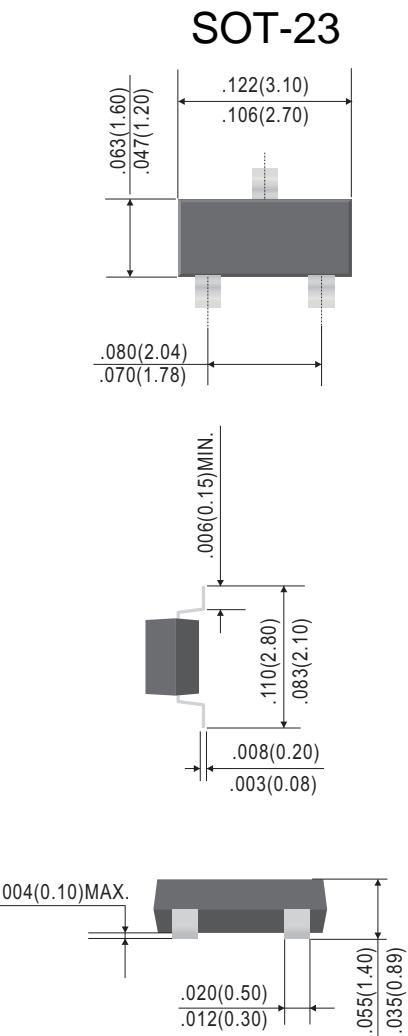
- Epoxy meets UL 94 V-0 flammability rating
- Moisture Sensitivity Level 1

## Absolute maximum ratings @ 25°C

Symbol	Parameter	Min	Typ	Max	Unit
$V_{CC}$	Supply voltage	---	50	---	V
$V_{IN}$	Input voltage	-5	---	+12	V
$P_d$	Power dissipation	---	200	---	mW
$T_j$	Junction temperature	---	150	---	°C
$T_{stg}$	Storage temperature	-55	---	150	°C
$I_o$	Output current		100		mA
$I_{C(MAX)}$			100		

## Electrical Characteristics @ 25°C

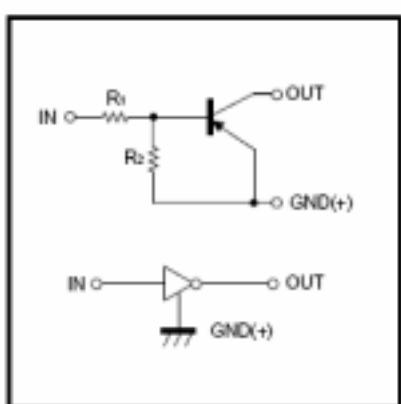
Symbol	Parameter	Min	Typ	Max	Unit
$V_{I(off)}$	Input voltage ( $V_{CC}=5V$ , $I_o=100 \mu A$ )	0.5	---	---	V
	( $V_o=0.3V$ , $I_o=5mA$ )	---	---	1.1	V
$V_{O(on)}$	Output voltage ( $I_o=5mA$ , $I_i=0.25mA$ )	---	0.1	0.3	V
$I_i$	Input current ( $V_i=5V$ )	---	---	3.6	mA
$I_{O(off)}$	Output current ( $V_{CC}=50V$ , $V_i=0$ )	---	---	0.5	μA
$G_I$	DC current gain ( $V_o=5V$ , $I_o=10mA$ )	80	---	---	
$R_1$	Input resistance	1.54	2.2	2.86	$K\Omega$
$R_2/R_1$	Resistance ratio	17	21	26	
$f_T$	Transition frequency ( $V_o=10V$ , $I_o=5mA$ , $f=100MHz$ )	---	250	---	MHz



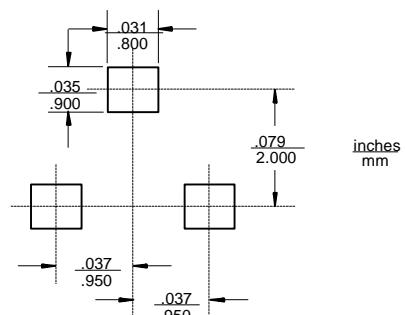
Dimensions in inches and (millimeters)

## Equivalent circuit

\*Marking: E32



## Suggested Solder Pad Layout





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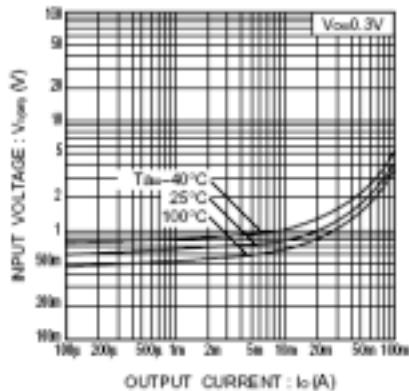


Fig.1 Input voltage vs. output current  
(ON characteristics)

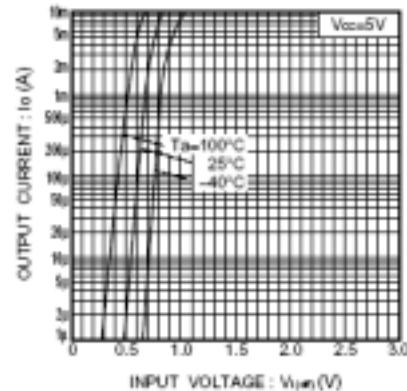


Fig.2 Output current vs. input voltage  
(OFF characteristics)

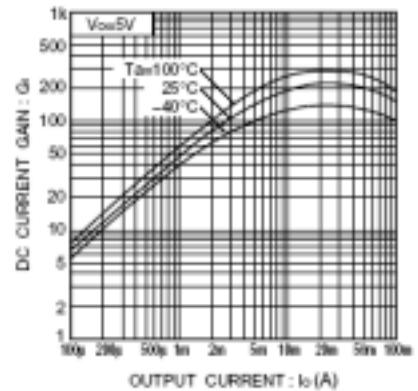


Fig.3 DC current gain vs. output current

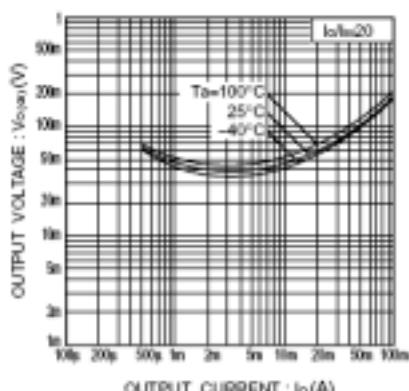


Fig.4 Output voltage vs. output current